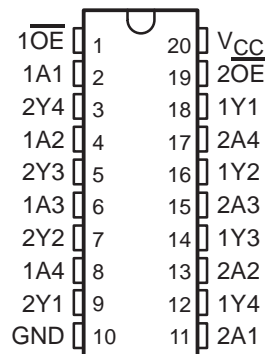


# SN54LVCH244A, SN74LVCH244A OCTAL BUFFERS/DRIVERS WITH 3-STATE OUTPUTS

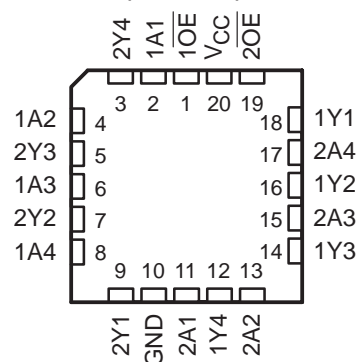
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- **EPIC™** (Enhanced-Performance Implanted CMOS) Submicron Process
- Typical  $V_{OLP}$  (Output Ground Bounce)  $< 0.8$  V at  $V_{CC} = 3.3$  V,  $T_A = 25^\circ\text{C}$
- Typical  $V_{OHV}$  (Output  $V_{OH}$  Undershoot)  $> 2$  V at  $V_{CC} = 3.3$  V,  $T_A = 25^\circ\text{C}$
- Power Off Disables Outputs, Permitting Live Insertion
- Support Mixed-Mode Signal Operation on All Ports (5-V Input/Output Voltage With 3.3-V  $V_{CC}$ )
- ESD Protection Exceeds 2000 V Per MIL-STD-883, Method 3015; Exceeds 200 V Using Machine Model ( $C = 200$  pF,  $R = 0$ )
- Latch-Up Performance Exceeds 250 mA Per JESD 17
- Bus Hold on Data Inputs Eliminates the Need for External Pullup/Pulldown Resistors
- Package Options Include Plastic Small-Outline (DW), Shrink Small-Outline (DB), and Thin Shrink Small-Outline (PW) Packages, Ceramic Flat (W) Package, Ceramic Chip Carriers (FK), and DIPs (J)

SN54LVCH244A . . . J OR W PACKAGE  
SN74LVCH244A . . . DB, DW, OR PW PACKAGE  
(TOP VIEW)



SN54LVCH244A . . . FK PACKAGE  
(TOP VIEW)



## description

The SN54LVCH244A octal buffer/line driver is designed for 2.7-V to 3.6-V  $V_{CC}$  operation and the SN74LVCH244A octal buffer/line driver is designed for 1.65-V to 3.6-V  $V_{CC}$  operation.

These devices are organized as two 4-bit line drivers with separate output-enable ( $\overline{OE}$ ) inputs. When  $\overline{OE}$  is low, these devices pass data from the A inputs to the Y outputs. When  $\overline{OE}$  is high, the outputs are in the high-impedance state.

Active bus-hold circuitry is provided to hold unused or floating data inputs at a valid logic level.

Inputs can be driven from either 3.3-V or 5-V devices. This feature allows the use of these devices as translators in a mixed 3.3-V/5-V system environment.

To ensure the high-impedance state during power up or power down,  $\overline{OE}$  should be tied to  $V_{CC}$  through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

The SN54LVCH244A is characterized for operation over the full military temperature range of  $-55^\circ\text{C}$  to  $125^\circ\text{C}$ . The SN74LVCH244A is characterized for operation from  $-40^\circ\text{C}$  to  $85^\circ\text{C}$ .



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PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.

**TEXAS  
INSTRUMENTS**

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On products compliant to MIL-PRF-38535, all parameters are tested unless otherwise noted. On all other products, production processing does not necessarily include testing of all parameters.

SN54LVCH244A, SN74LVCH244A

OCTAL BUFFERS/DRIVERS

WITH 3-STATE OUTPUTS

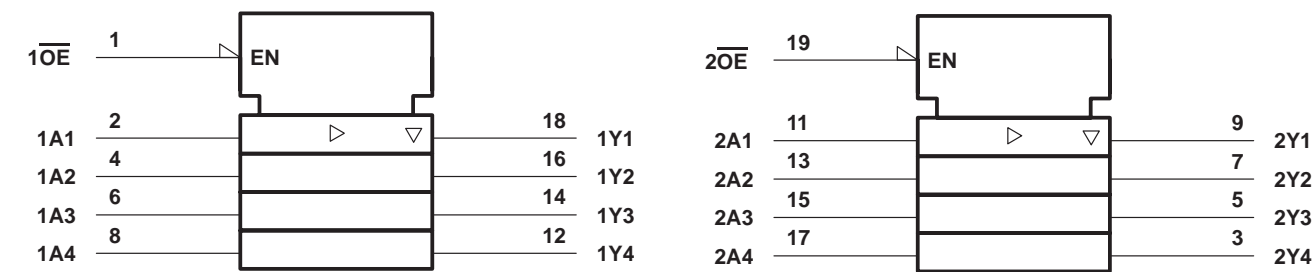
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FUNCTION TABLE

(each buffer)

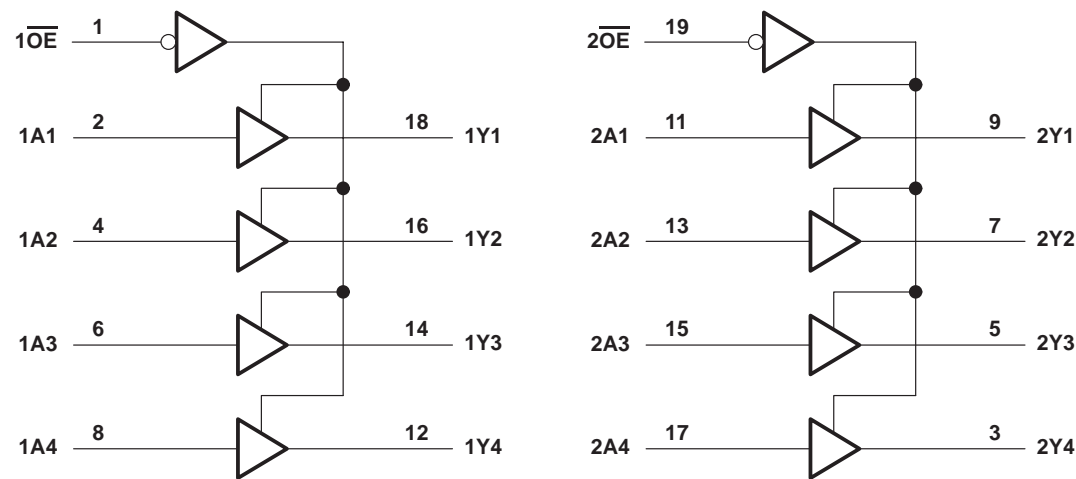
INPUTS		OUTPUT Y
$\overline{\text{OE}}$	A	
L	H	H
L	L	L
H	X	Z

logic symbol†



† This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

logic diagram (positive logic)



# SN54LVCH244A, SN74LVCH244A

## OCTAL BUFFERS/DRIVERS

### WITH 3-STATE OUTPUTS

SCES009G – JULY 1995 - REVISED JUNE 1998

#### absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, $V_{CC}$	–0.5 V to 6.5 V
Input voltage range, $V_I$ (see Note 1)	–0.5 V to 6.5 V
Voltage range applied to any output in the high-impedance or power-off state, $V_O$ (see Note 1)	–0.5 V to 6.5 V
Voltage range applied to any output in the high or low state, $V_O$ (see Notes 1 and 2)	–0.5 V to $V_{CC} + 0.5$ V
Input clamp current, $I_{IK}$ ( $V_I < 0$ )	–50 mA
Output clamp current, $I_{OK}$ ( $V_O < 0$ )	–50 mA
Continuous output current, $I_O$	±50 mA
Continuous current through $V_{CC}$ or GND	±100 mA
Package thermal impedance, $\theta_{JA}$ (see Note 3): DB package	115°C/W
DW package	97°C/W
PW package	128°C/W
Storage temperature range, $T_{stg}$	–65°C to 150°C

† Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.  
2. The value of  $V_{CC}$  is provided in the recommended operating conditions table.  
3. The package thermal impedance is calculated in accordance with JESD 51.

#### recommended operating conditions (see Note 4)

		SN54LVCH244A		SN74LVCH244A		UNIT
		MIN	MAX	MIN	MAX	
$V_{CC}$ Supply voltage	Operating	2	3.6	1.65	3.6	V
	Data retention only	1.5		1.5		
$V_{IH}$ High-level input voltage	$V_{CC} = 1.65$ V to $1.95$ V			$0.65 \times V_{CC}$		V
	$V_{CC} = 2.3$ V to $2.7$ V			1.7		
	$V_{CC} = 2.7$ V to $3.6$ V	2		2		
$V_{IL}$ Low-level input voltage	$V_{CC} = 1.65$ V to $1.95$ V			$0.35 \times V_{CC}$		V
	$V_{CC} = 2.3$ V to $2.7$ V			0.7		
	$V_{CC} = 2.7$ V to $3.6$ V		0.8	0.8		
$V_I$ Input voltage		0	5.5	0	5.5	V
$V_O$ Output voltage	High or low state	0	$V_{CC}$	0	$V_{CC}$	V
	3 state	0	5.5	0	5.5	
$I_{OH}$ High-level output current	$V_{CC} = 1.65$ V			–4		mA
	$V_{CC} = 2.3$ V			–8		
	$V_{CC} = 2.7$ V		–12	–12		
	$V_{CC} = 3$ V		–24	–24		
$I_{OL}$ Low-level output current	$V_{CC} = 1.65$ V			4		mA
	$V_{CC} = 2.3$ V			8		
	$V_{CC} = 2.7$ V		12	12		
	$V_{CC} = 3$ V		24	24		
$\Delta t/\Delta v$ Input transition rise or fall rate		0	10	0	10	ns/V
$T_A$ Operating free-air temperature		–55	125	–40	85	°C

NOTE 4: All unused control inputs of the device must be held at  $V_{CC}$  or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.



# SN54LVCH244A, SN74LVCH244A

## OCTAL BUFFERS/DRIVERS

### WITH 3-STATE OUTPUTS

SCES009G – JULY 1995 - REVISED JUNE 1998

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS		V <sub>CC</sub>	SN54LVCH244A			SN74LVCH244A			UNIT
				MIN	TYP†	MAX	MIN	TYP†	MAX	
V <sub>OH</sub>	I <sub>OH</sub> = −100 μA		1.65 V to 3.6 V				V <sub>CC</sub> −0.2			V
			2.7 V to 3.6 V	V <sub>CC</sub> −0.2						
	I <sub>OH</sub> = −4 mA		1.65 V				1.2			
	I <sub>OH</sub> = −8 mA		2.3 V				1.7			
	I <sub>OH</sub> = −12 mA		2.7 V	2.2			2.2			
			3 V	2.4			2.4			
	I <sub>OH</sub> = −24 mA		3 V	2.2			2.2			
V <sub>OL</sub>	I <sub>OL</sub> = 100 μA		1.65 V to 3.6 V				0.2			V
			2.7 V to 3.6 V	0.2						
	I <sub>OL</sub> = 4 mA		1.65 V				0.45			
	I <sub>OL</sub> = 8 mA		2.3 V				0.7			
	I <sub>OL</sub> = 12 mA		2.7 V	0.4			0.4			
	I <sub>OL</sub> = 24 mA		3 V	0.55			0.55			
I <sub>I</sub>	V <sub>I</sub> = 0 to 5.5 V		3.6 V	±5			±5			μA
I <sub>off</sub>	V <sub>I</sub> or V <sub>O</sub> = 5.5 V		0				±10			μA
I <sub>I</sub> (hold)	V <sub>I</sub> = 0.58 V		1.65 V				‡			μA
	V <sub>I</sub> = 1.07 V						‡			
	V <sub>I</sub> = 0.7 V		2.3 V				45			
	V <sub>I</sub> = 1.7 V						−45			
I <sub>I</sub> (hold)	V <sub>I</sub> = 0.8 V		3 V	75			75			μA
	V <sub>I</sub> = 2 V			−75			−75			
	V <sub>I</sub> = 0 to 3.6 V§		3.6 V	±500			±500			
I <sub>OZ</sub>	V <sub>O</sub> = 0 to 5.5 V		3.6 V	±15			±10			μA
I <sub>CC</sub>	V <sub>I</sub> = V <sub>CC</sub> or GND		3.6 V	10			10			μA
	3.6 V ≤ V <sub>I</sub> ≤ 5.5 V¶			10			10			
ΔI <sub>CC</sub>	One input at V <sub>CC</sub> − 0.6 V, Other inputs at V <sub>CC</sub> or GND		2.7 V to 3.6 V	500			500			μA
C <sub>i</sub>	V <sub>I</sub> = V <sub>CC</sub> or GND		3.3 V	4 12			4			pF
C <sub>O</sub>	V <sub>O</sub> = V <sub>CC</sub> or GND		3.3 V	5.5 12			5.5			pF

† All typical values are at V<sub>CC</sub> = 3.3 V, T<sub>A</sub> = 25°C.

‡ This information was not available at the time of publication.

§ This is the bus-hold maximum dynamic current required to switch the input from one state to another.

¶ This applies in the disabled state only.



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**SN54LVCH244A, SN74LVCH244A**  
**OCTAL BUFFERS/DRIVERS**  
**WITH 3-STATE OUTPUTS**

SCES009G – JULY 1995 - REVISED JUNE 1998

**switching characteristics over recommended operating free-air temperature range (unless otherwise noted) (see Figure 3)**

PARAMETER	FROM (INPUT)	TO (OUTPUT)	SN54LVCH244A				UNIT
			V <sub>CC</sub> = 2.7 V		V <sub>CC</sub> = 3.3 V ± 0.3 V		
			MIN	MAX	MIN	MAX	
t <sub>pd</sub>	A	Y	7.5		1	6.5	ns
t <sub>en</sub>	$\overline{\text{OE}}$	Y	9		1	8	ns
t <sub>dis</sub>	$\overline{\text{OE}}$	Y	8		1	7	ns

**switching characteristics over recommended operating free-air temperature range (unless otherwise noted) (see Figures 1 through 3)**

PARAMETER	FROM (INPUT)	TO (OUTPUT)	SN74LVCH244A								UNIT
			V <sub>CC</sub> = 1.8 V ± 0.15 V		V <sub>CC</sub> = 2.5 V ± 0.2 V		V <sub>CC</sub> = 2.7 V		V <sub>CC</sub> = 3.3 V ± 0.3 V		
			MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t <sub>pd</sub>	A	Y	†	†	†	†	6.9		1.5	5.9	ns
t <sub>en</sub>	$\overline{\text{OE}}$	Y	†	†	†	†	8.6		1	7.6	ns
t <sub>dis</sub>	$\overline{\text{OE}}$	Y	†	†	†	†	6.8		1.5	5.8	ns

† This information was not available at the time of publication.

**operating characteristics, T<sub>A</sub> = 25°C**

PARAMETER			TEST CONDITIONS	V <sub>CC</sub> = 1.8 V ± 0.15 V	V <sub>CC</sub> = 2.5 V ± 0.2 V	V <sub>CC</sub> = 3.3 V ± 0.3 V	UNIT
				TYP	TYP	TYP	
C <sub>pd</sub>	Power dissipation capacitance per buffer/driver	Outputs enabled	f = 10 MHz	†	†	47	pF
		Outputs disabled		†	†	2	

† This information was not available at the time of publication.

# SN54LVCH244A, SN74LVCH244A

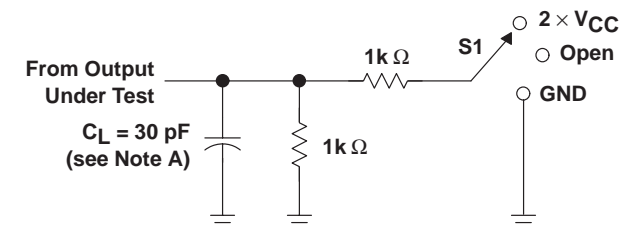
## OCTAL BUFFERS/DRIVERS

### WITH 3-STATE OUTPUTS

SCES009G – JULY 1995 - REVISED JUNE 1998

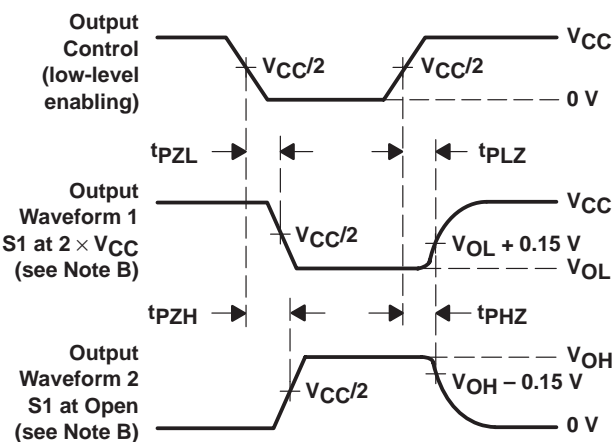
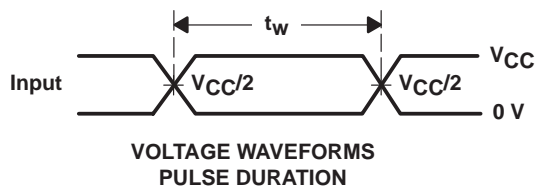
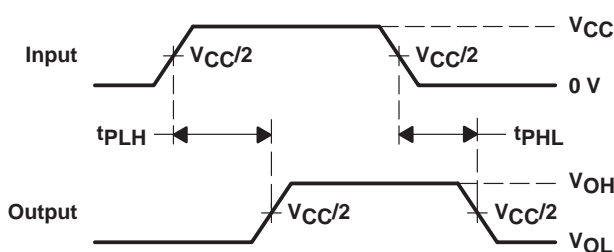
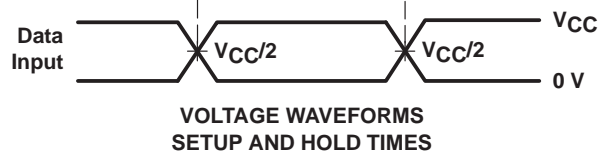
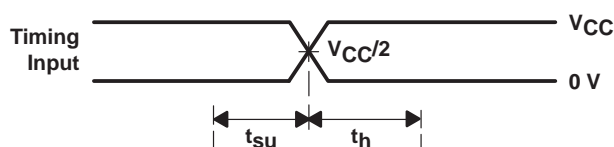
#### PARAMETER MEASUREMENT INFORMATION

$$V_{CC} = 1.8 \text{ V} \pm 0.15 \text{ V}$$



LOAD CIRCUIT

TEST	S1
$t_{pd}$	Open
$t_{PLZ}/t_{PZL}$	$2 \times V_{CC}$
$t_{PHZ}/t_{PHZ}$	Open

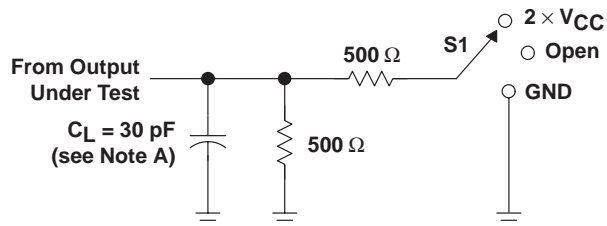


- NOTES:
- $C_L$  includes probe and jig capacitance.
  - Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
  - All input pulses are supplied by generators having the following characteristics:  $PRR \leq 10 \text{ MHz}$ ,  $Z_O = 50 \Omega$ ,  $t_r \leq 2 \text{ ns}$ ,  $t_f \leq 2 \text{ ns}$ .
  - The outputs are measured one at a time with one transition per measurement.
  - $t_{PLZ}$  and  $t_{PHZ}$  are the same as  $t_{dis}$ .
  - $t_{PZL}$  and  $t_{PZH}$  are the same as  $t_{en}$ .
  - $t_{PLH}$  and  $t_{PHL}$  are the same as  $t_{pd}$ .

Figure 1. Load Circuit and Voltage Waveforms

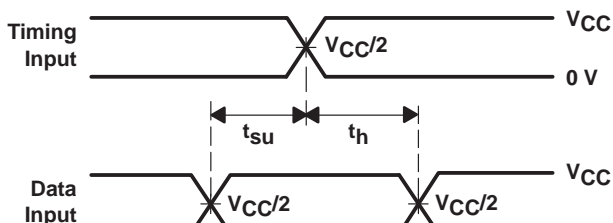
# PARAMETER MEASUREMENT INFORMATION

$$V_{CC} = 2.5 \text{ V} \pm 0.2 \text{ V}$$

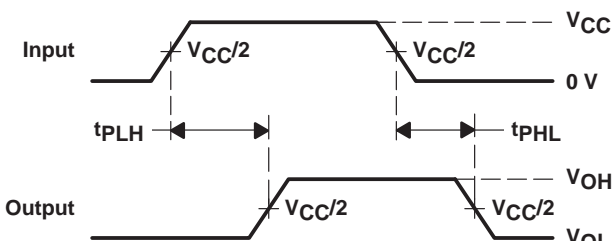


LOAD CIRCUIT

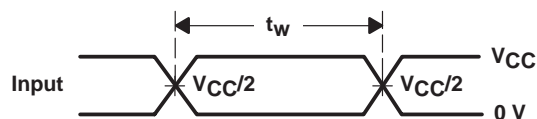
TEST	S1
$t_{pd}$	Open
$t_{PLZ}/t_{PZL}$	2 $\times V_{CC}$
$t_{PHZ}/t_{PZH}$	GND



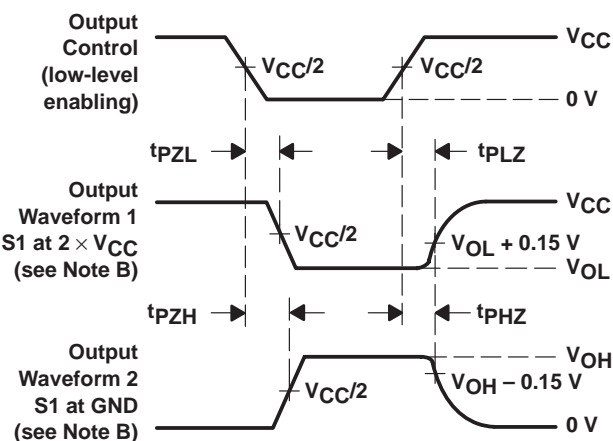
VOLTAGE WAVEFORMS  
SETUP AND HOLD TIMES



VOLTAGE WAVEFORMS  
PROPAGATION DELAY TIMES



VOLTAGE WAVEFORMS  
PULSE DURATION



VOLTAGE WAVEFORMS  
ENABLE AND DISABLE TIMES

- NOTES: A.  $C_L$  includes probe and jig capacitance.
- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics:  $PRR \leq 10 \text{ MHz}$ ,  $Z_O = 50 \Omega$ ,  $t_r \leq 2 \text{ ns}$ ,  $t_f \leq 2 \text{ ns}$ .
- D. The outputs are measured one at a time with one transition per measurement.
- E.  $t_{PLZ}$  and  $t_{PHZ}$  are the same as  $t_{dis}$ .
- F.  $t_{PZL}$  and  $t_{PZH}$  are the same as  $t_{en}$ .
- G.  $t_{PLH}$  and  $t_{PHL}$  are the same as  $t_{pd}$ .

Figure 2. Load Circuit and Voltage Waveforms

# SN54LVCH244A, SN74LVCH244A

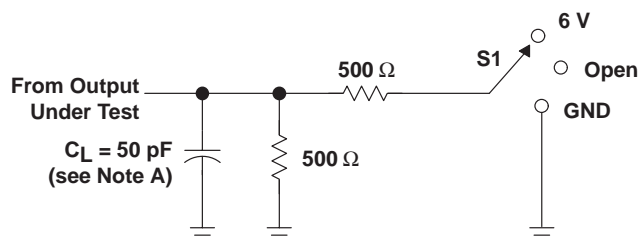
## OCTAL BUFFERS/DRIVERS

### WITH 3-STATE OUTPUTS

SCES009G – JULY 1995 - REVISED JUNE 1998

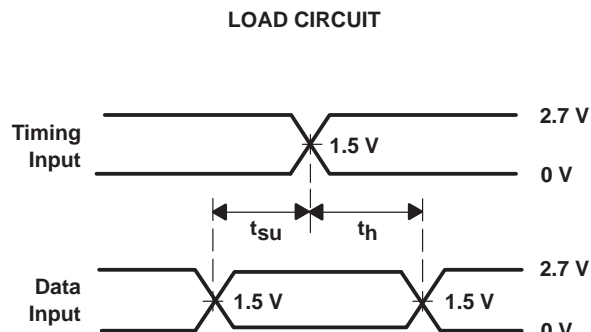
#### PARAMETER MEASUREMENT INFORMATION

$V_{CC} = 2.7\text{ V AND } 3.3\text{ V} \pm 0.3\text{ V}$

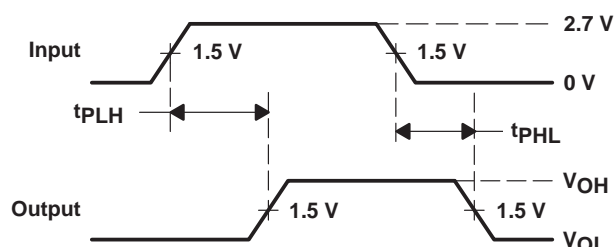


LOAD CIRCUIT

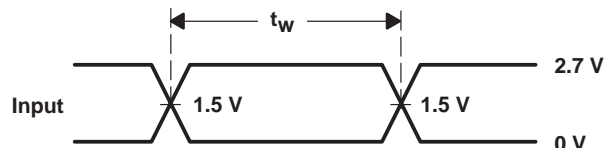
TEST	S1
$t_{pd}$	Open
$t_{PLZ}/t_{PZL}$	6 V
$t_{PHZ}/t_{PZH}$	GND



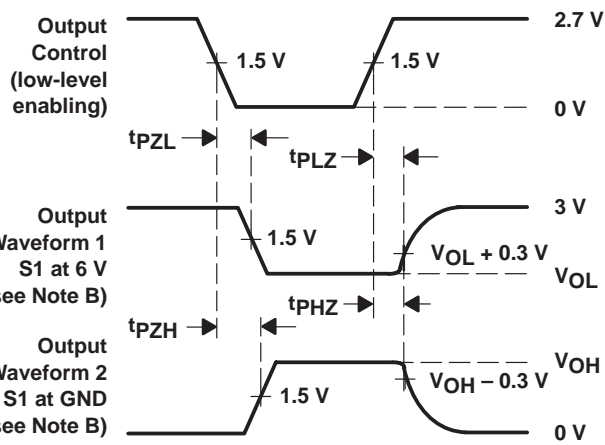
VOLTAGE WAVEFORMS  
SETUP AND HOLD TIMES



VOLTAGE WAVEFORMS  
PROPAGATION DELAY TIMES



VOLTAGE WAVEFORMS  
PULSE DURATION



VOLTAGE WAVEFORMS  
ENABLE AND DISABLE TIMES

- NOTES:
- $C_L$  includes probe and jig capacitance.
  - Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
  - All input pulses are supplied by generators having the following characteristics:  $PRR \leq 10\text{ MHz}$ ,  $Z_O = 50\text{ }\Omega$ ,  $t_r \leq 2.5\text{ ns}$ ,  $t_f \leq 2.5\text{ ns}$ .
  - The outputs are measured one at a time with one transition per measurement.
  - $t_{PLZ}$  and  $t_{PHZ}$  are the same as  $t_{dis}$ .
  - $t_{PZL}$  and  $t_{PZH}$  are the same as  $t_{en}$ .
  - $t_{PLH}$  and  $t_{PHL}$  are the same as  $t_{pd}$ .

Figure 3. Load Circuit and Voltage Waveforms



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